

Dirac Plasmons in Topological Insulators

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Acknowledgements

Terahertz Experiments

Marta Autore, Fausto D'Apuzzo, Flavio
Giorgianni, Paola Di Pietro, Odeta Limaj,
Stefano Lupi

Sapienza University and INFN, Rome



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Bi₂Se₃ film growth

Sean Oh, Matthew Brahlek
Rutgers University, New Jersey (USA)



RUTGERS

Plasmonic array Fabrication

Alessandra Di Gaspare, Valeria Giliberti,
and Michele Ortolani

INFN, CNR-IFN, Sapienza University Rome (IT)



IFN

Institute for Photonics and Nanotechnologies

High Magnetic Field Experiments

Hans Engelkamp
HFML Nijmegen (NL)

Theory

Javier García de Abajo, IQFR-CSIC (EE)
Marco Polini, CNR-Pisa (IT)

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Terahertz Experiments

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Andrea Rov

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MA



HFML Nijmegen, (NL)

Marco Polini, CNR-Pisa (IT)

FR-CSIC (SPAIN)

and Nanotechnologies

Outline

- 1. Properties of 3D Topological Insulators;**
- 2. Introduction to Plasmonics;**
- 3. Observation of Terahertz Dirac Plasmons in TIs:**
 - TI Ribbon-Array Plasmons in a strong magnetic field;
 - TI Ring-Array Plasmons;

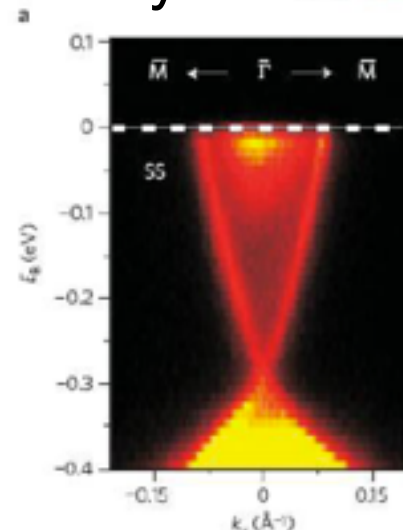
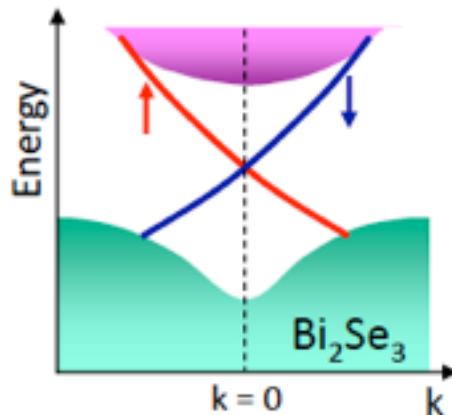
Physical properties of TIs



An insulator with non trivial topology cannot be smoothly transformed into a trivial insulator \rightarrow there must be a **Quantum Phase Transition** at the boundary in which the insulating gap goes to zero

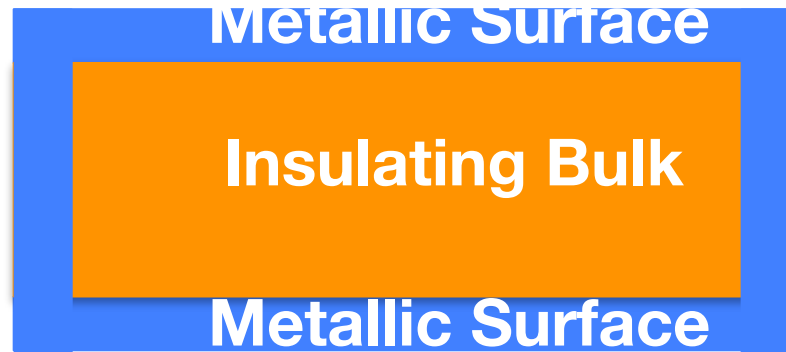


Presence of **metallic edge states** at the interface with vacuum or any trivial dielectric

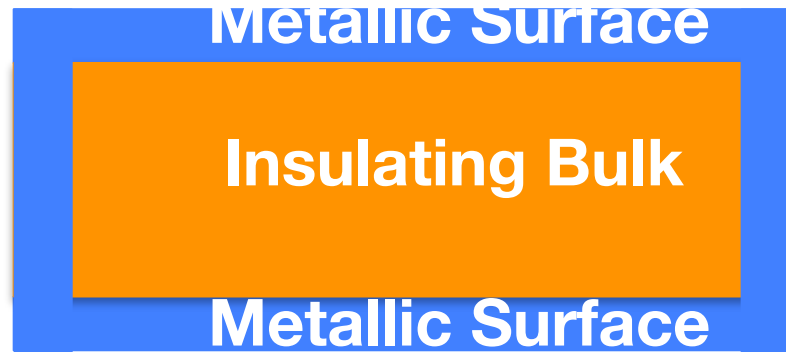


Xia et al, Nature Physics 2009

Topological Insulators



Topological Insulators

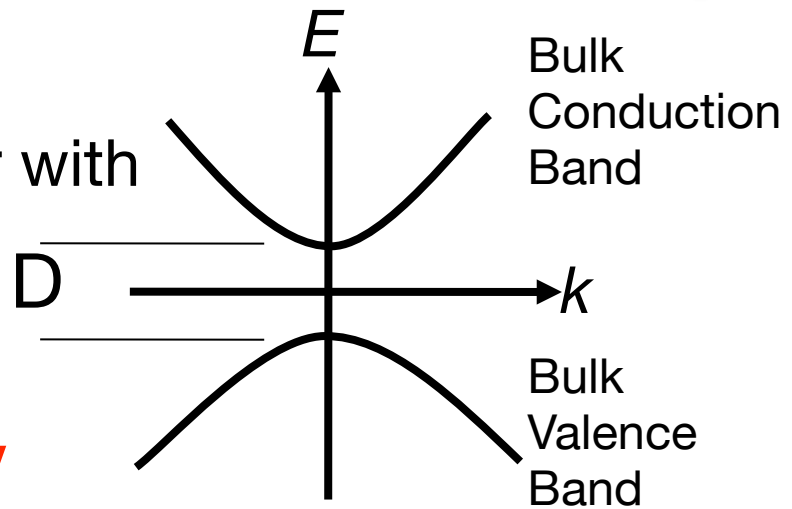


Bulk band insulator

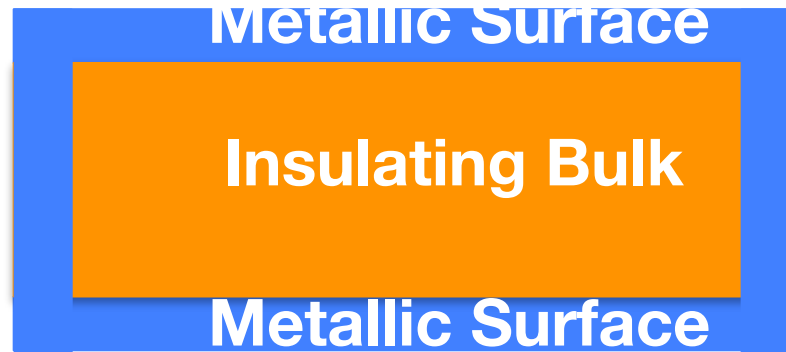
Gapped bulk insulator with massive particles

$$E \approx k^2$$

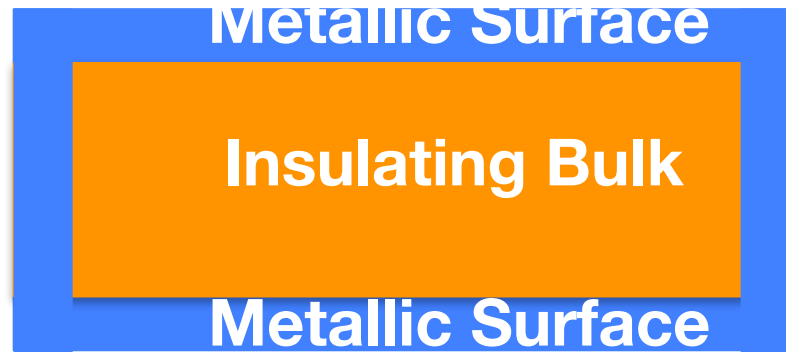
$$\Delta \approx 300 \text{ meV}$$



Topological Insulators



Topological Insulators



Topological Insulators

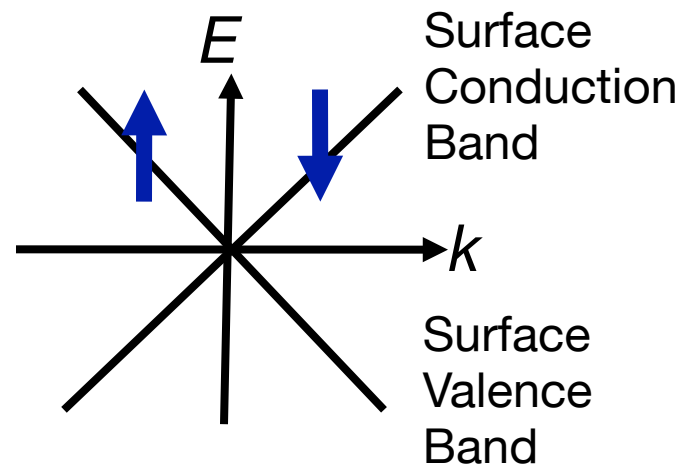


Gapless Dirac surface states

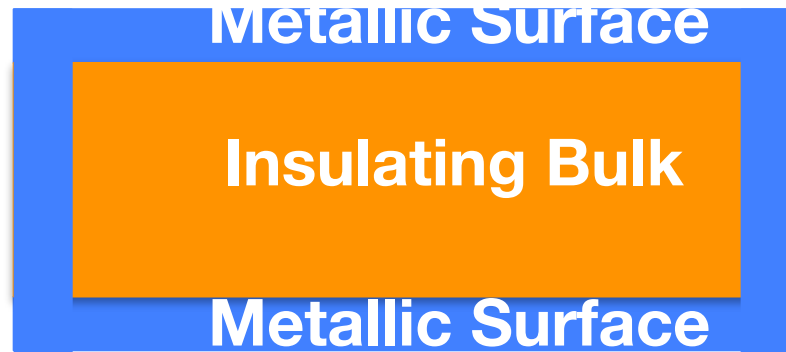
$$E \approx k$$

Properties:

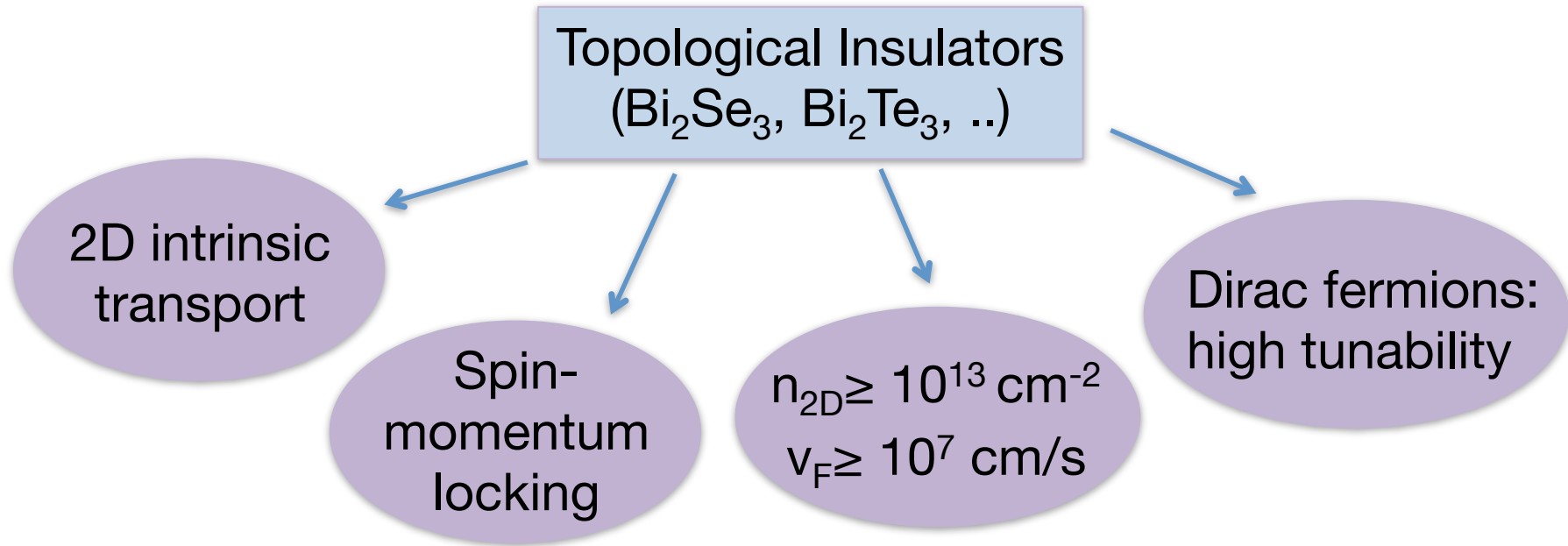
Spin locked to Momentum;
Backscattering protection;
Superconductivity



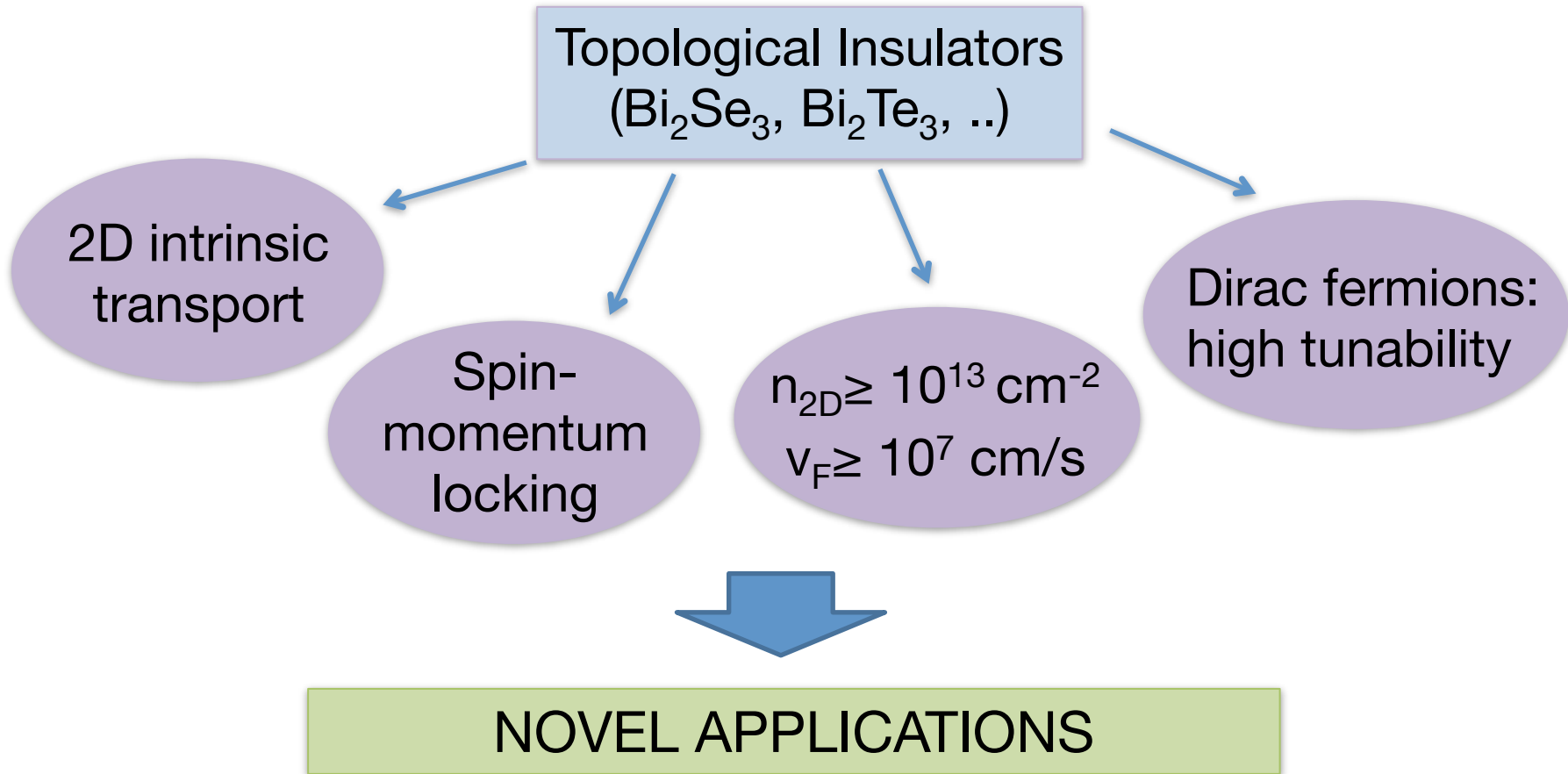
Topological Insulators



TIs for novel applications



TIs for novel applications



Spintronics

GMR valves, magnetic QU-bits

Plasmonics

Biosensing, light subwavelength confinement, THz sensors

Outline

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3. Observation of Terahertz Dirac Plasmons in TIs:

- TI Ribbon-Array Plasmons in a strong magnetic field;
- TI Ring-Array Plasmons;

Plasmons

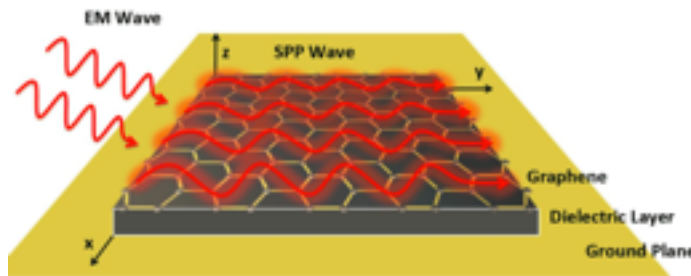
Plasma oscillations = density fluctuations of free-electrons

$$\omega_p \propto k$$

Plasmons on 2D electron systems

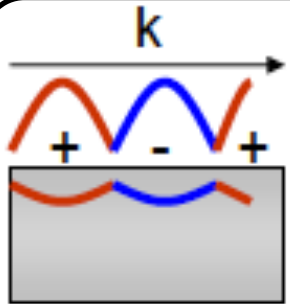
on 2DEG or
graphene

$$\omega_p \propto \sqrt{k}$$



Plasmons

Plasma oscillations = density fluctuations of free-electrons



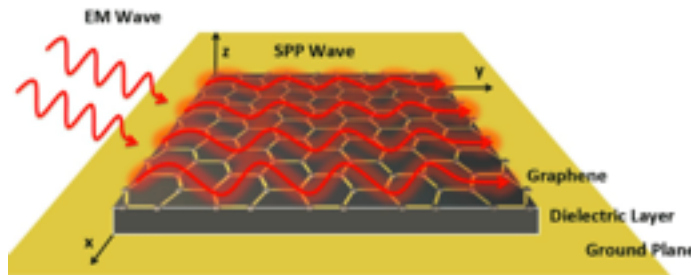
Plasmons at the interface between a metal and a dielectric can strongly interact with light forming propagating hybrid mode: Surface-Plasmon-Polariton

$$\omega_p \propto k$$

Plasmons on 2D electron systems

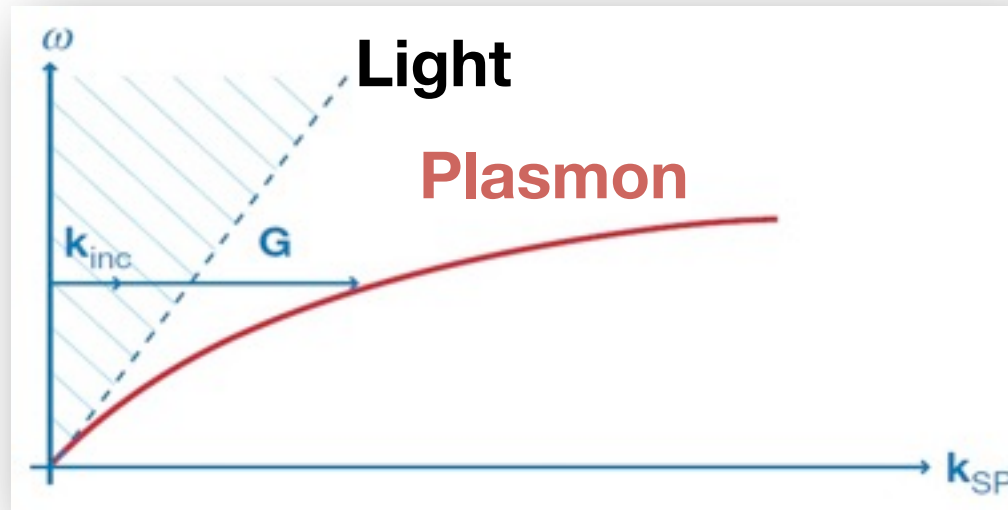
on 2DEG or graphene

$$\omega_p \propto \sqrt{k}$$



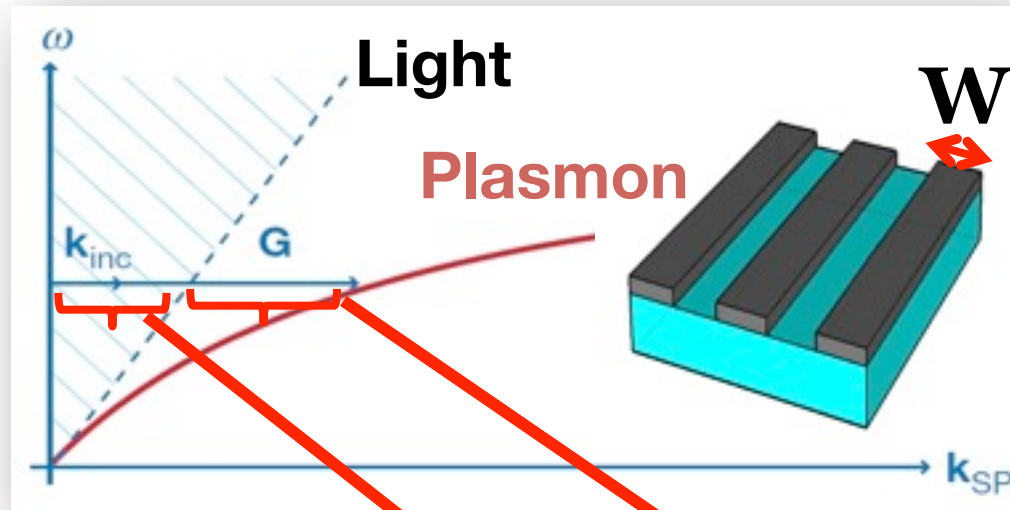
Light Excitation of Plasmons

Additional Wave-vector \rightarrow micro/nano-structures



Light Excitation of Plasmons

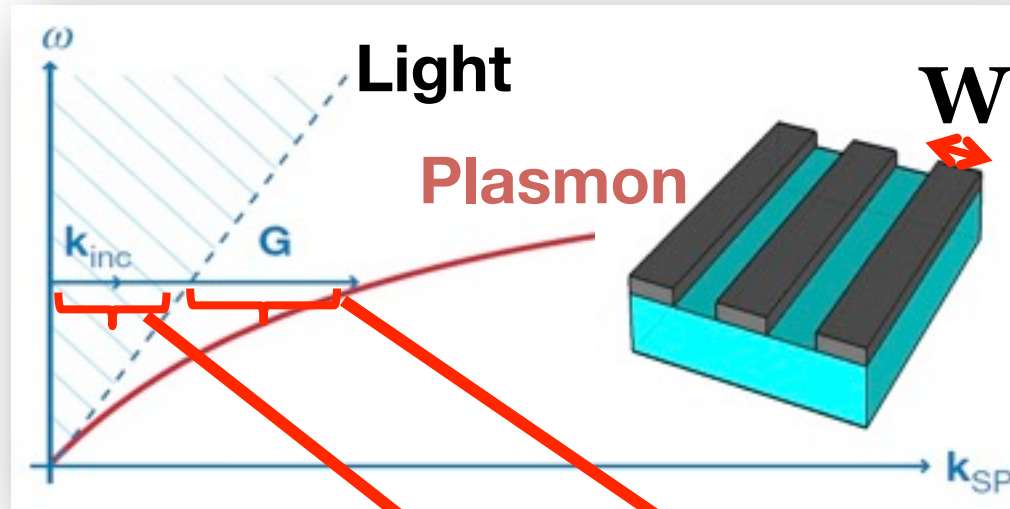
Additional Wave-vector \rightarrow micro/nano-structures



$$k_P = k_{light} + \frac{\pi}{W}$$

Light Excitation of Plasmons

Additional Wave-vector \rightarrow micro/nano-structures



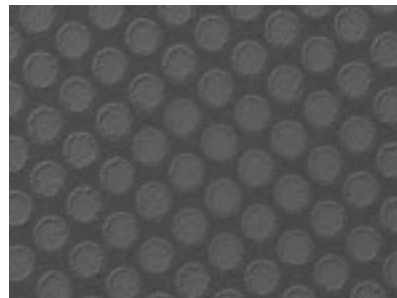
Ribbons



$$k_P = k_{light} + \frac{\pi}{W}$$

The equation is presented with k_{light} and $\frac{\pi}{W}$ enclosed in red boxes. Red arrows point from these boxes to the corresponding parts of the dispersion diagram above.

Disks



Rings



Plasmons

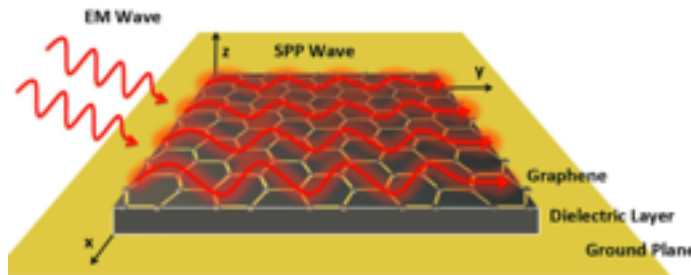
Plasma oscillations = density fluctuations of free-electrons

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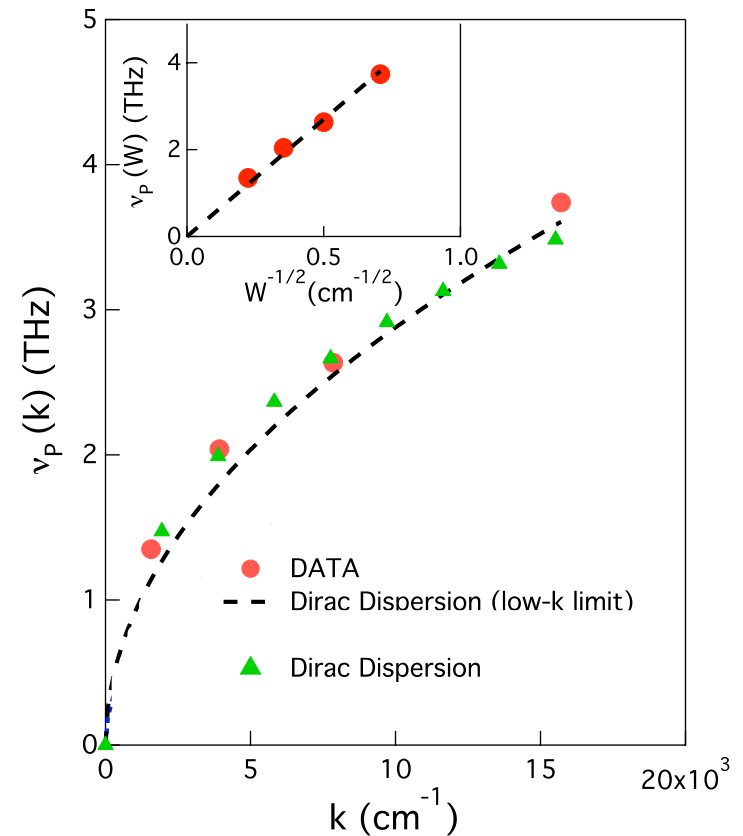
Plasmons on 2D electron systems

on 2DEG or
graphene

$$\omega_p \propto \sqrt{k}$$



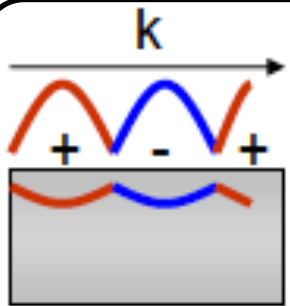
Bi_2Se_3 microribbon arrays



P. Di. Pietro *et al.*, Nature Nanotech. 8, 556 (2013)

Plasmons

Plasma oscillations = density fluctuations of free-electrons



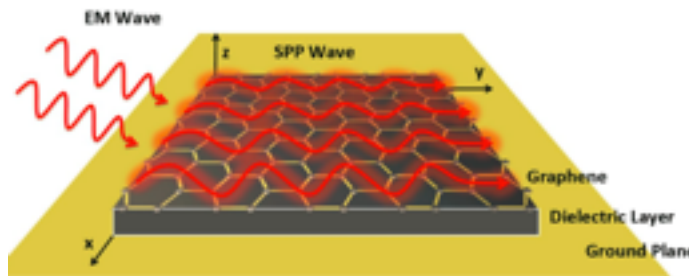
Plasmons at the interface between a metal and a dielectric can strongly interact with light forming propagating hybrid mode: Surface-Plasmon-Polariton

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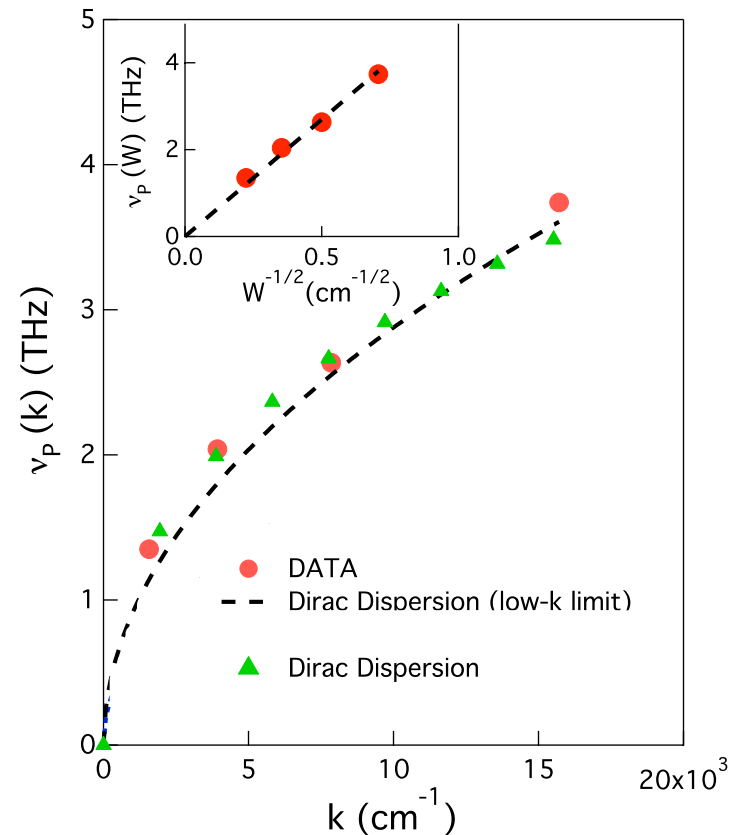
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TI Ribbon-Plasmons in a strong magnetic field (I)

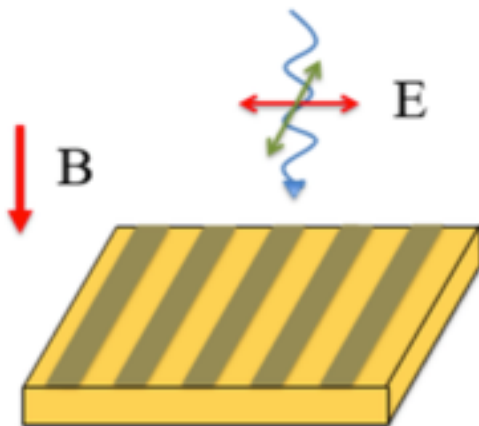
In Topological Insulators the cyclotron frequency is comparable to the Plasmon frequency (for micrometric patterning)



First observation of magnetoplasmons on TIs

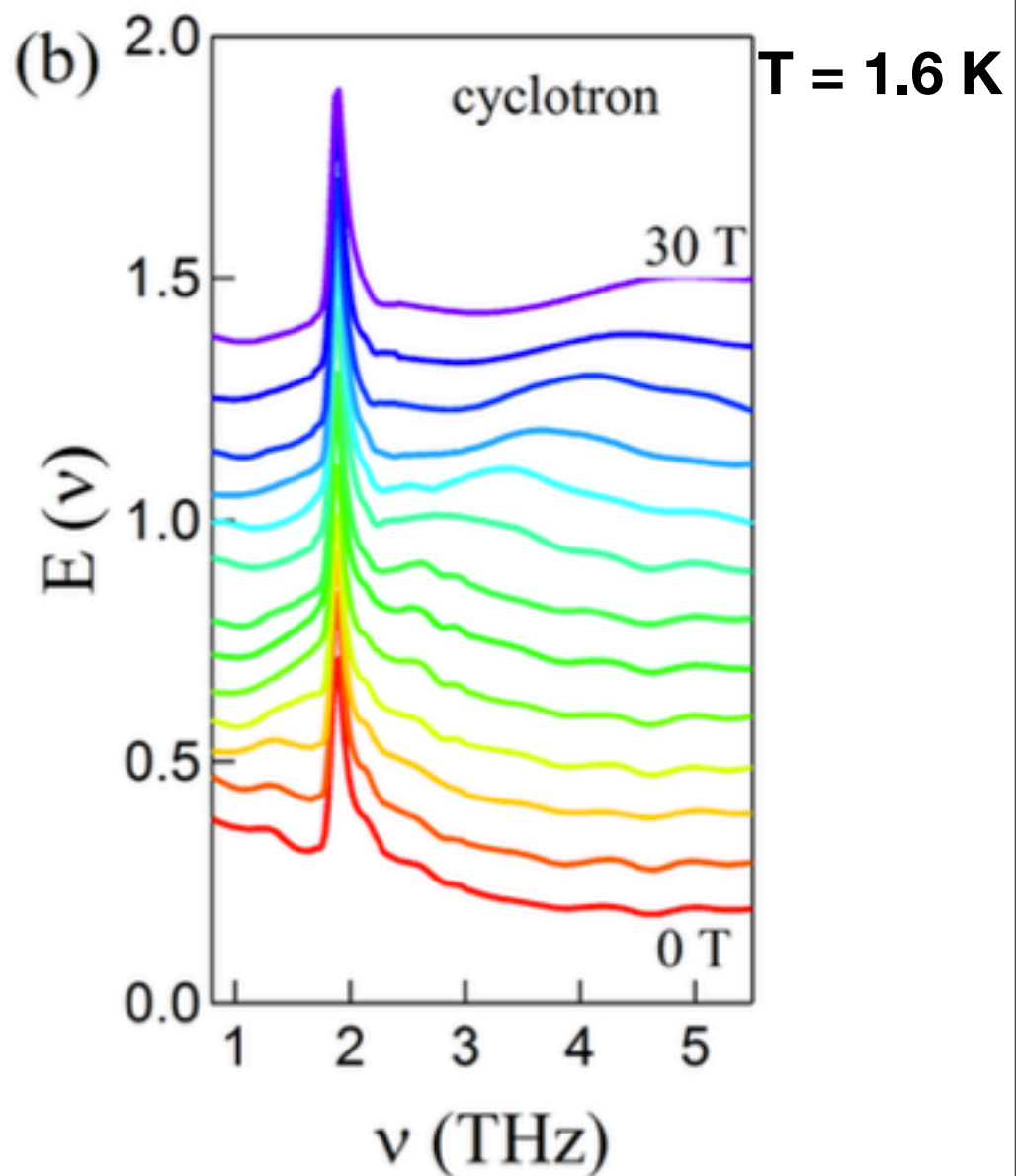
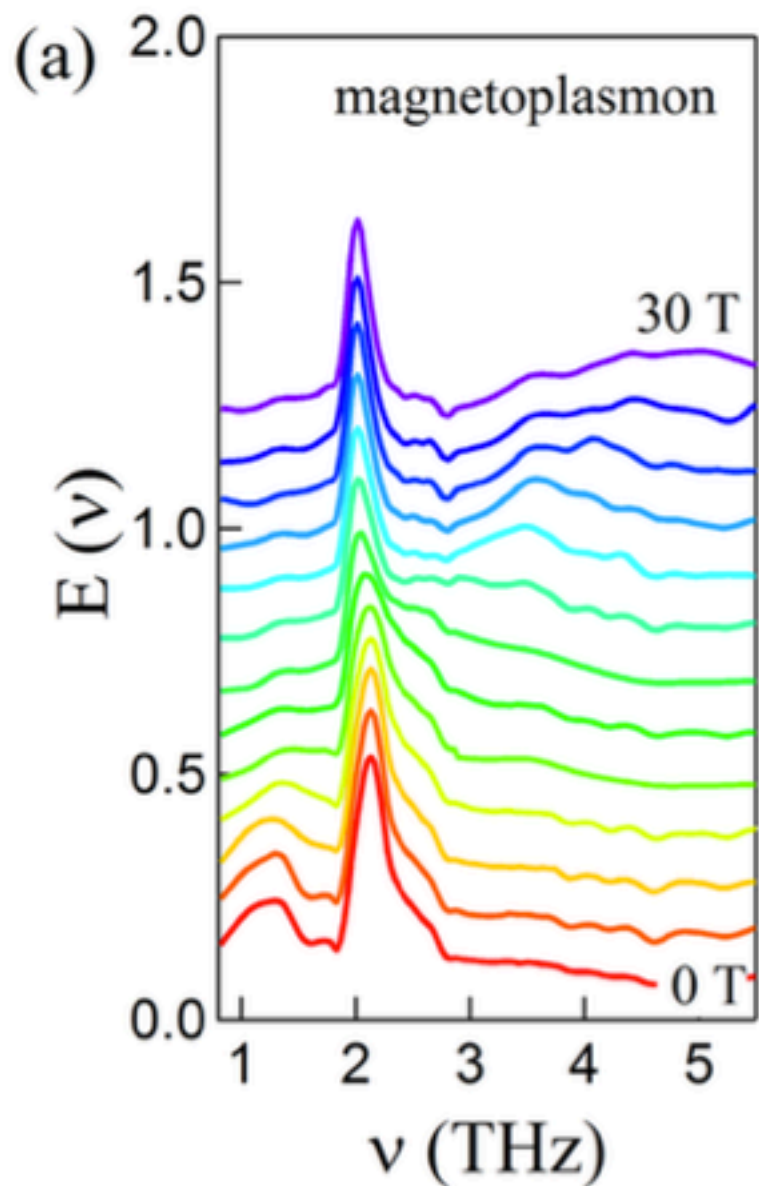


Measure of the cyclotron mass



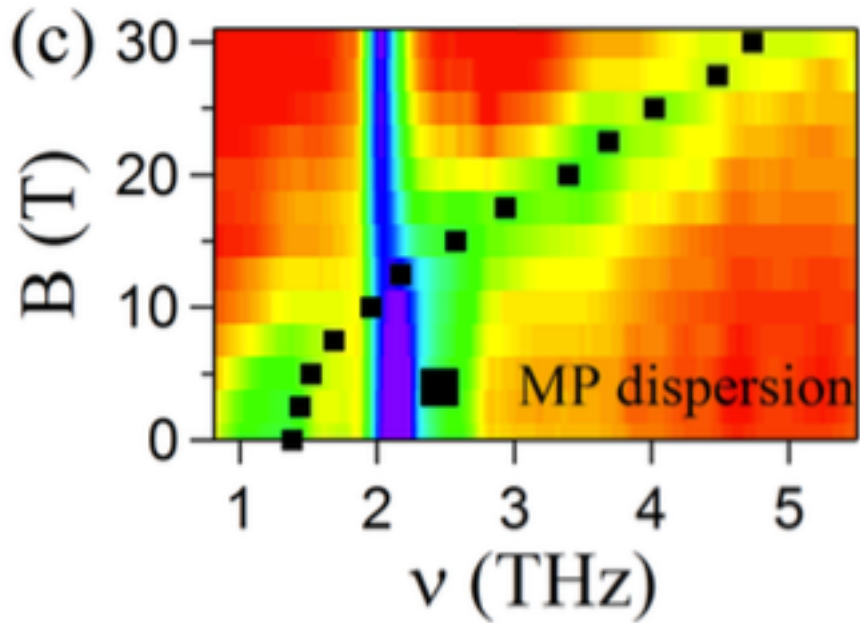
Terahertz Spectroscopy in Faraday configuration from 700 GHz to 7 THz at 1.2 K and from 0 to 30 T at HMFL-Nijmegen (NL) on Bi_2Se_3 ribbon arrays

TI Ribbon-Plasmons in a strong magnetic field (II)

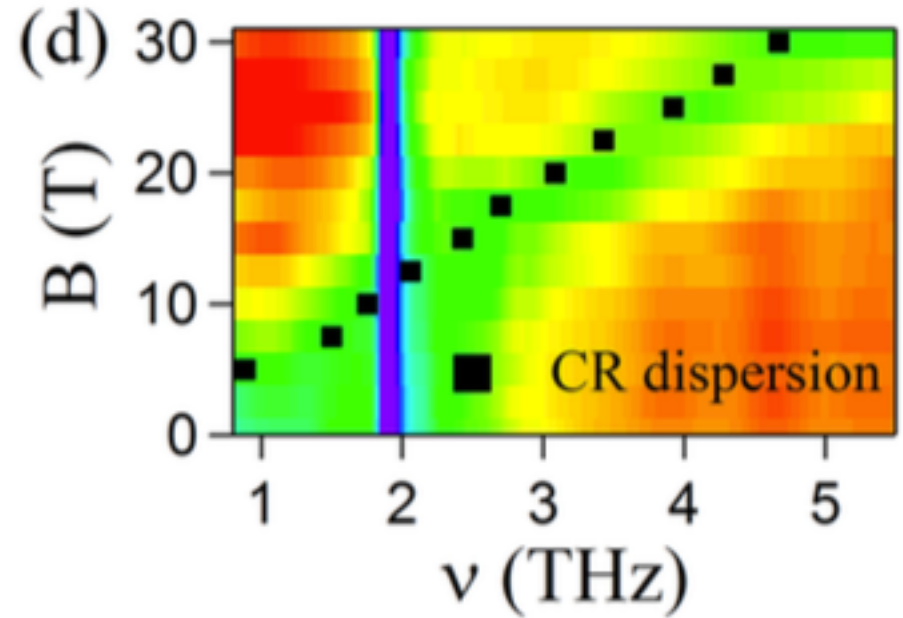


M. Autore et al., *ACS Photonics* **2**, 1231–1235 (2015)

TI Ribbon-Plasmons in a strong magnetic field (III)



data fitted by Fano model



data fitted by Drude model in magnetic field

Magnetoplasmon frequency

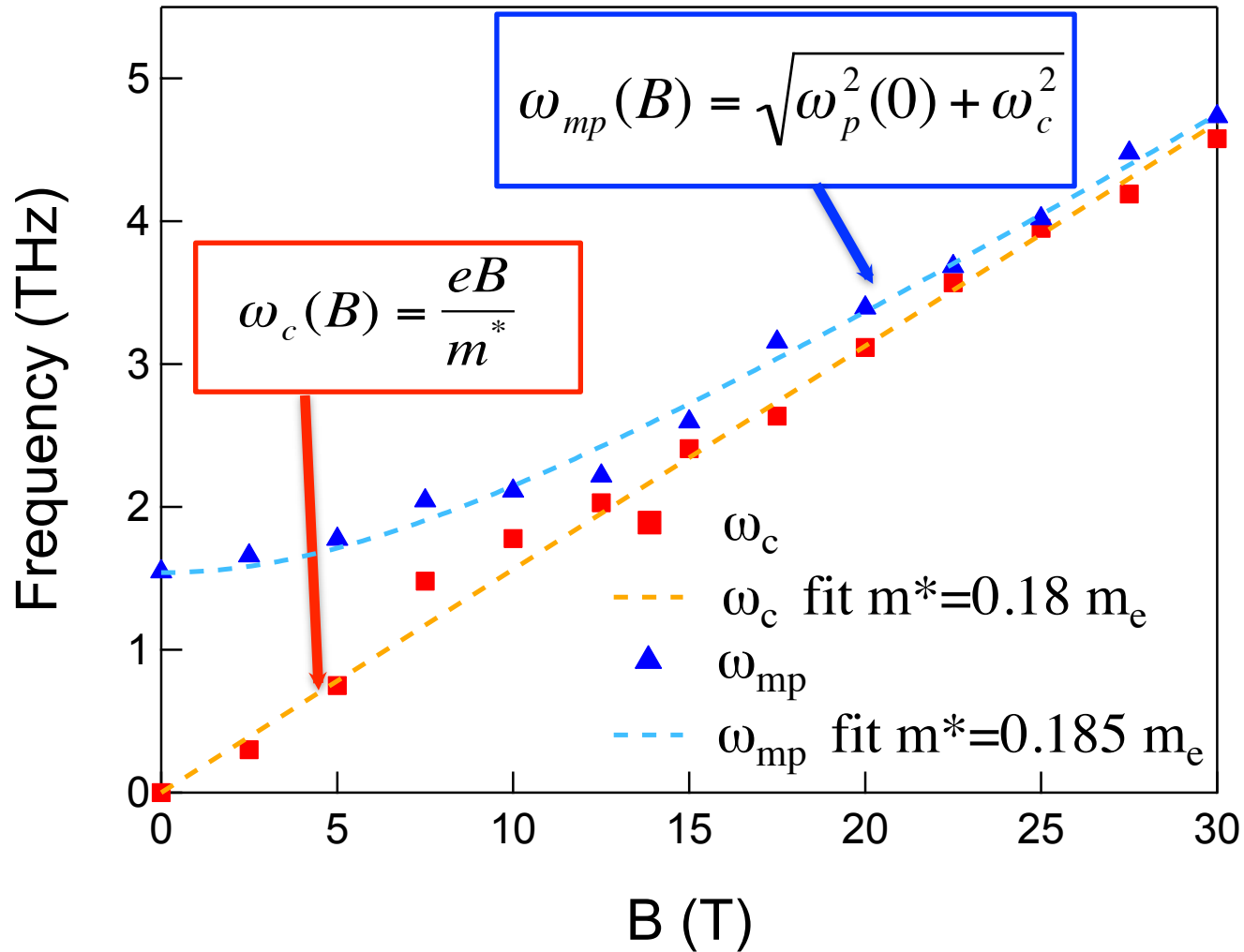
$$\omega_{mp}(B) = \sqrt{\omega_p^2 + \omega_c^2}$$

Cyclotron frequency

$$\omega_c = \frac{eB}{m^*}$$

M. Autore et al., *ACS Photonics* **2**, 1231–1235 (2015)

TI Ribbon-Plasmons in a strong magnetic field (IV)



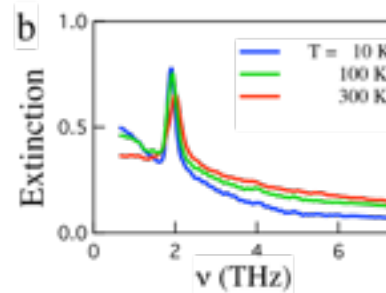
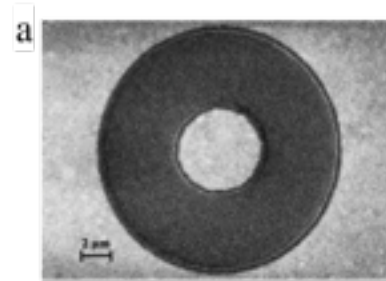
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Outline

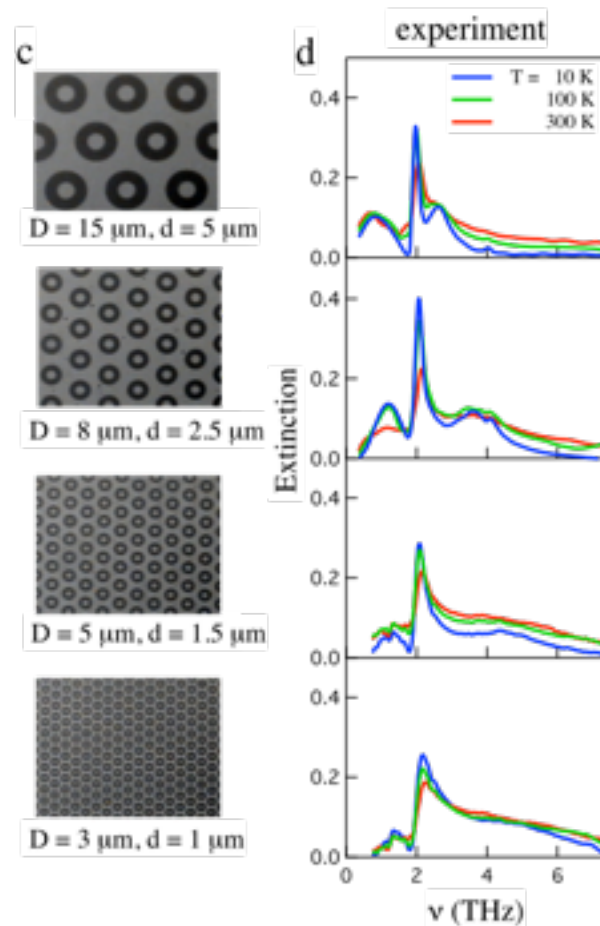
1. Introduction to Plasmonics;
2. Properties of 3D Topological Insulators;
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- i) TI Ribbon-Array Plasmons;
- ii) TI Ribbon-Array Plasmons in a strong magnetic field;
- ii) TI Ring-Array Plasmons;**

Plasmons in Bi_2Se_3 Ring-Arrays: data



Drude-Lorentz
response for
unpatterned samples



M. Autore et al., Adv. Opt. Mat. **3**, 9 (2015)

Plasmons in Bi_2Se_3 Ring-Arrays

Plasmon-Plasmon hybridization



$D = 15 \mu\text{m}$, $d = 5 \mu\text{m}$



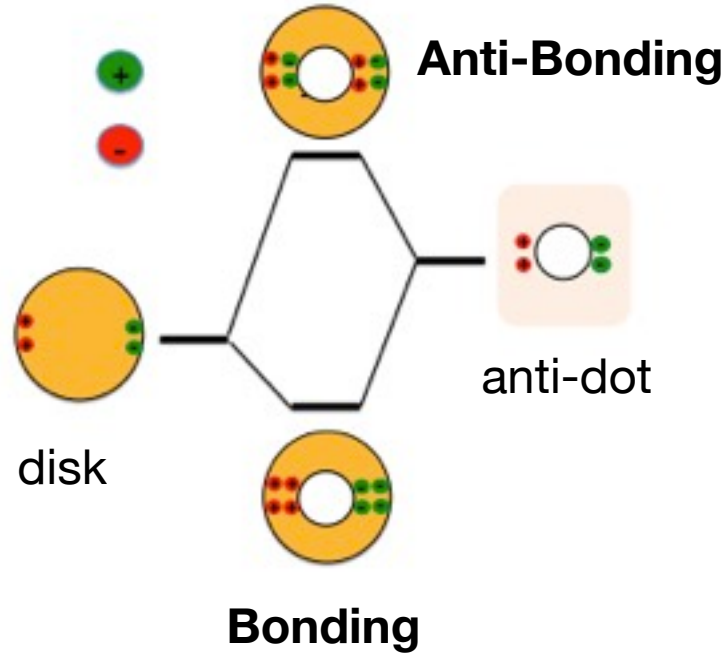
$D = 8 \mu\text{m}$, $d = 2.5 \mu\text{m}$



$D = 5 \mu\text{m}$, $d = 1.5 \mu\text{m}$



$D = 3 \mu\text{m}$, $d = 1 \mu\text{m}$



Plasmons in Bi_2Se_3 Ring-Arrays

Plasmon-Plasmon hybridization
+
Plasmon-Phonon hybridization



$D = 15 \mu\text{m}, d = 5 \mu\text{m}$



$D = 8 \mu\text{m}, d = 2.5 \mu\text{m}$

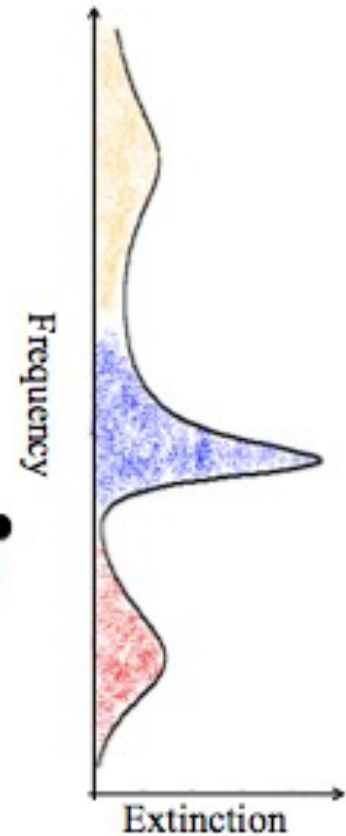
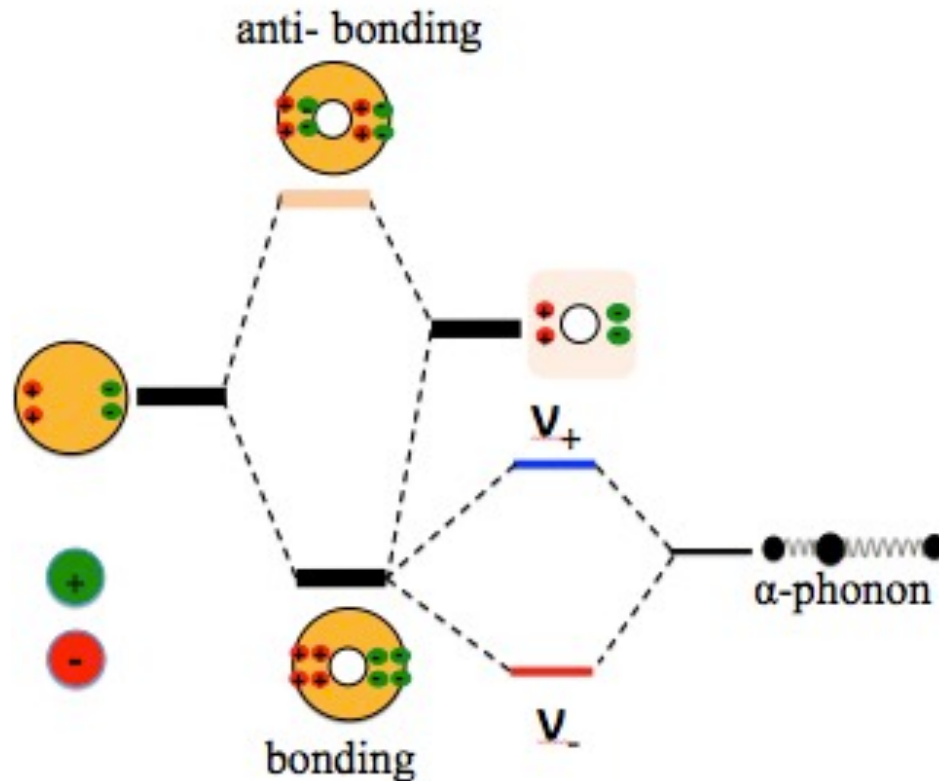


$D = 5 \mu\text{m}, d = 1.5 \mu\text{m}$



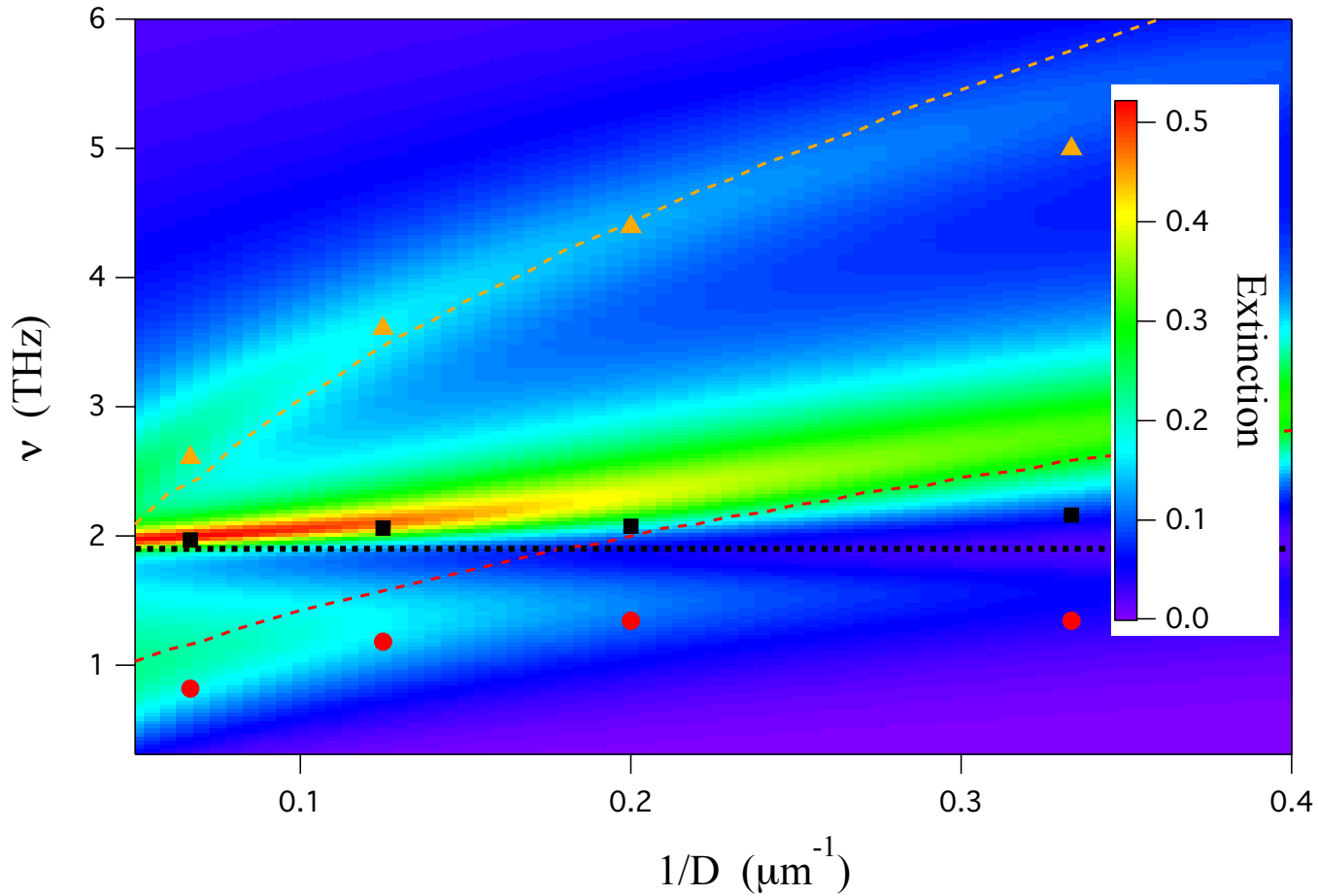
$D = 3 \mu\text{m}, d = 1 \mu\text{m}$

$F(\omega)$



Plasmons in Bi_2Se_3 Ring Arrays: data vs model

(in collaboration with F. J. García de Abajo, ICFO Barcelona)



Bonding and antibonding plasmons if we artificially switch off the phonon

M. Autore et al., Adv. Opt. Mat. **3**, 9 (2015)

Conclusion

- We have Dirac 2D plasmons on the surface of TIs;
- Plasmons survive at room-T;
- Tunability via B field, hybridization, pl-ph coupling make TIs a good platform for plasmonics

Perspectives



- Modulation of plasmon absorption through an electrostatic gating → THz devices;
- Magneto-optical measurements;
- THz Time Resolved Spectroscopy → Plasmon lifetime; Spin-channel excitations;

Spin-charge
oscillations

Al_2O_3

Conclusion

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Perspectives



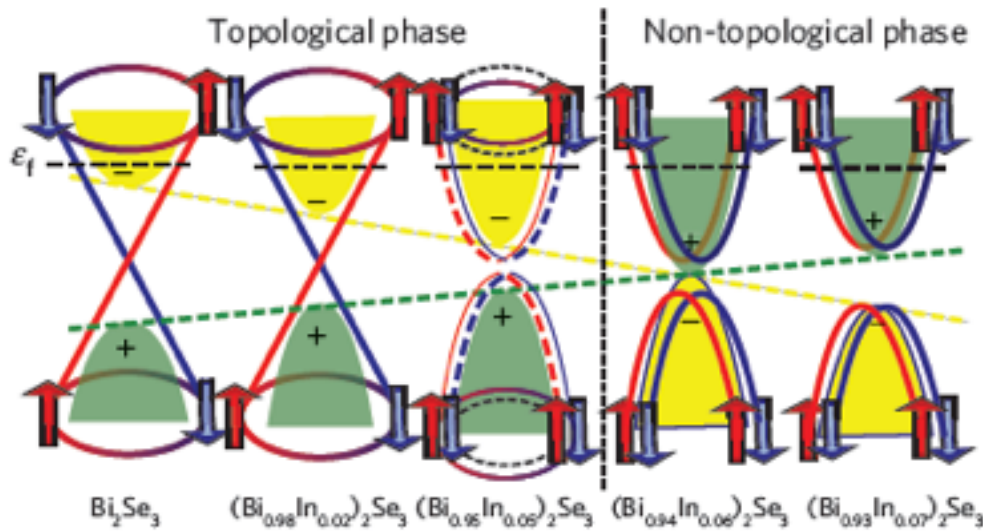
- Modulation of plasmon absorption through an electrostatic gating → THz devices;
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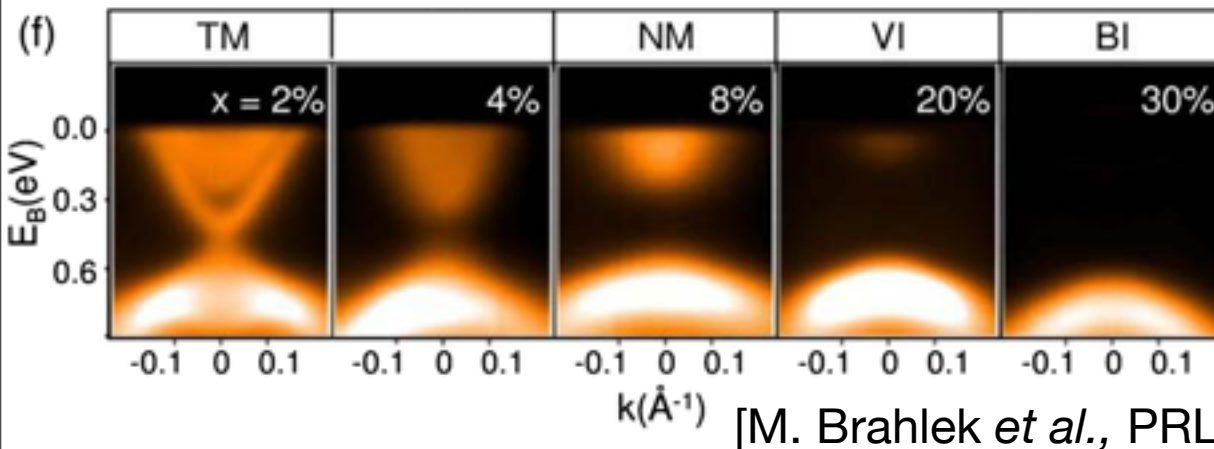
Thank you for your attention!

Collective excitations through Topological Phase Transition in $(\text{Bi}_{1-x}\text{In}_x)_2\text{Se}_3$ (I)

A Topological Phase Transition occurs between $x=0.03$ and $x=0.07$
 [L. Wu *et al.*, Nature Phys. 9, 410 (2013)]

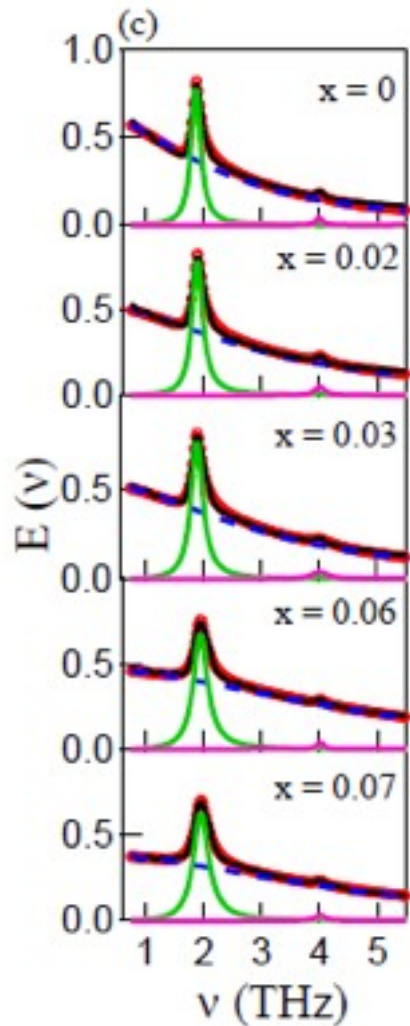


What happens to collective excitations through the transition?



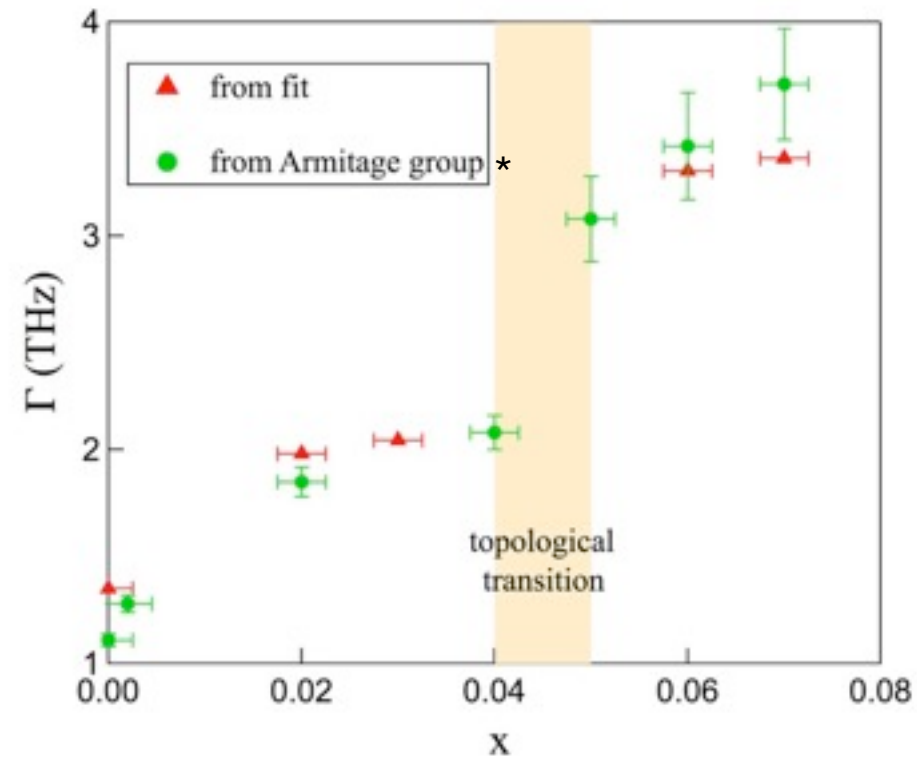
Collective excitations through Topological Phase Transition in $(\text{Bi}_{1-x}\text{In}_x)_2\text{Se}_3$ (II)

Firstly we studied single particle excitations in $(\text{Bi}_{1-x}\text{In}_x)_2\text{Se}_3$ thin films with several x values



Drude-Lorentz fits allowed us to extract the single particle scattering rate

*[L. Wu *et al.*, Nature Phys. 9, 410 (2013)]

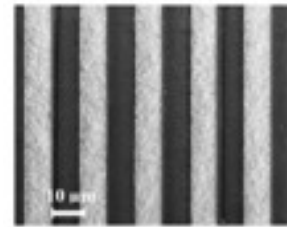
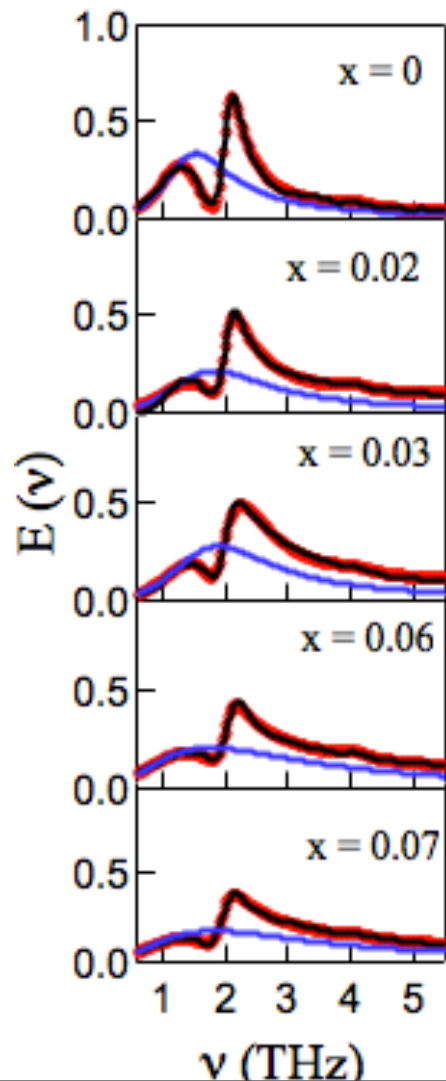


A sudden collapse in the single particle lifetime appears across the topological transition as a loss of topological protection

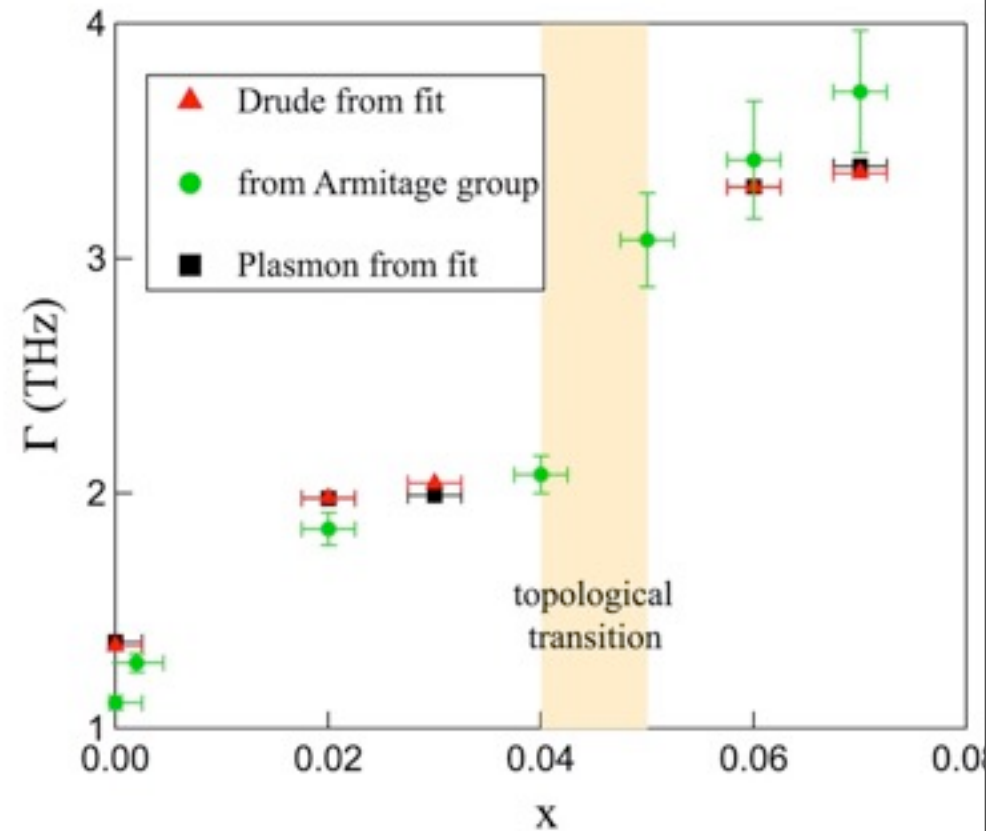
M. Autore *et al.*, submitted to NanoScale (2015)

Collective excitations through Topological Phase Transition in $(\text{Bi}_{1-x}\text{In}_x)_2\text{Se}_3$ (II)

We studied plasmon excitations in ribbon arrays of $(\text{Bi}_{1-x}\text{In}_x)_2\text{Se}_3$ with $W=8\mu\text{m}$ and several x values



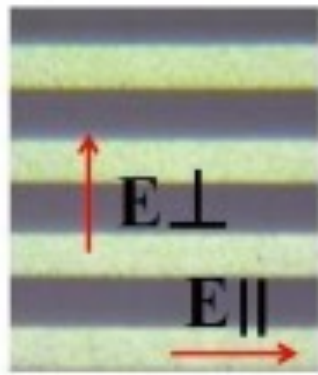
Fano fits allowed us to extract the plasmon scattering rate



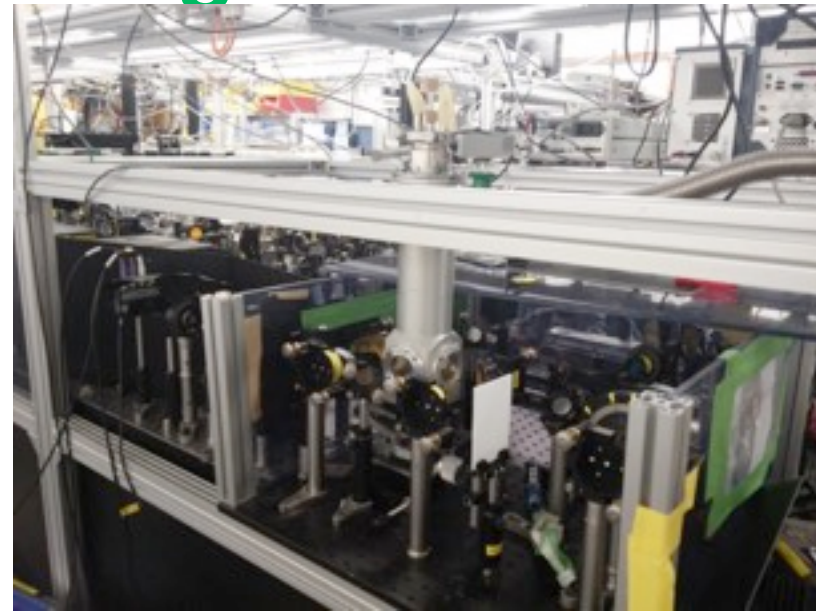
Same behavior as single particles
→ strong indication of topological protection of collective modes

M. Autore *et al.*, submitted to NanoScale (2015)

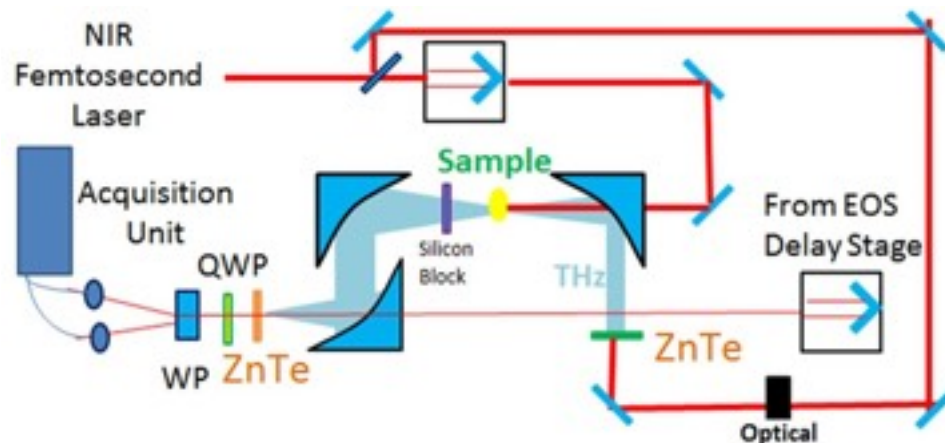
Time-Resolved THz dynamics of Dirac Plasmon in Bi₂Se₃ Topological Insulator



$d = 120 \text{ QL}$ $W = 8 \mu\text{m}$



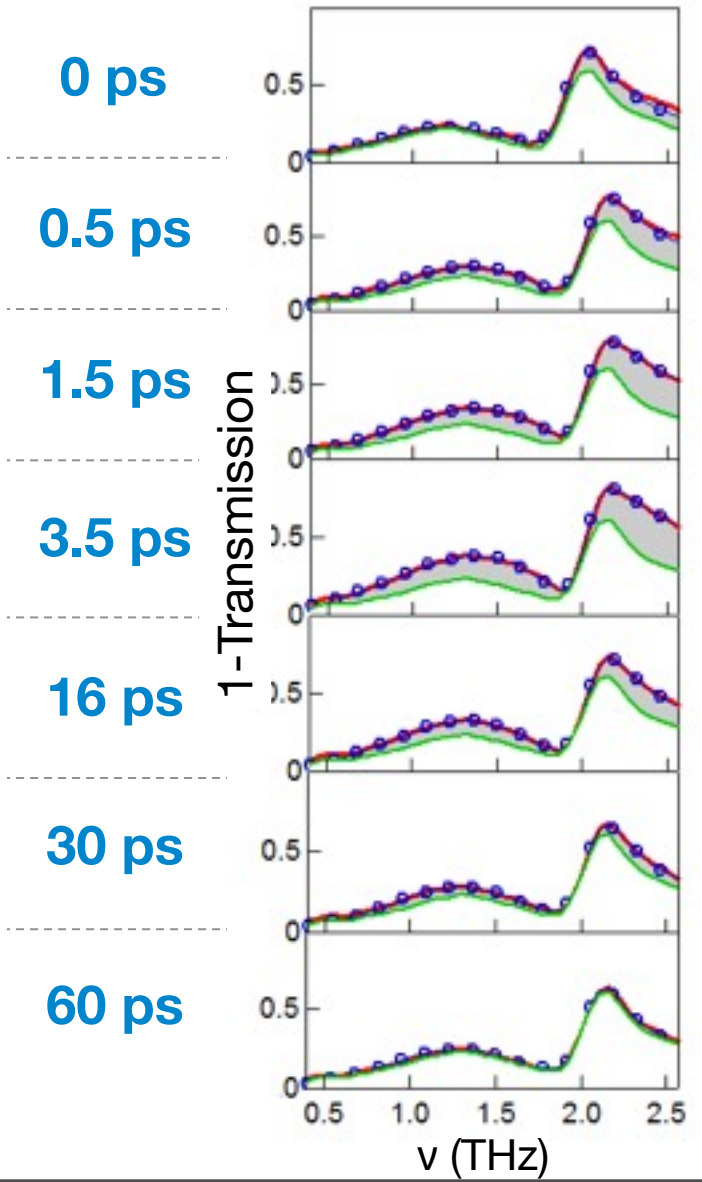
Optical-Pump THz-Probe



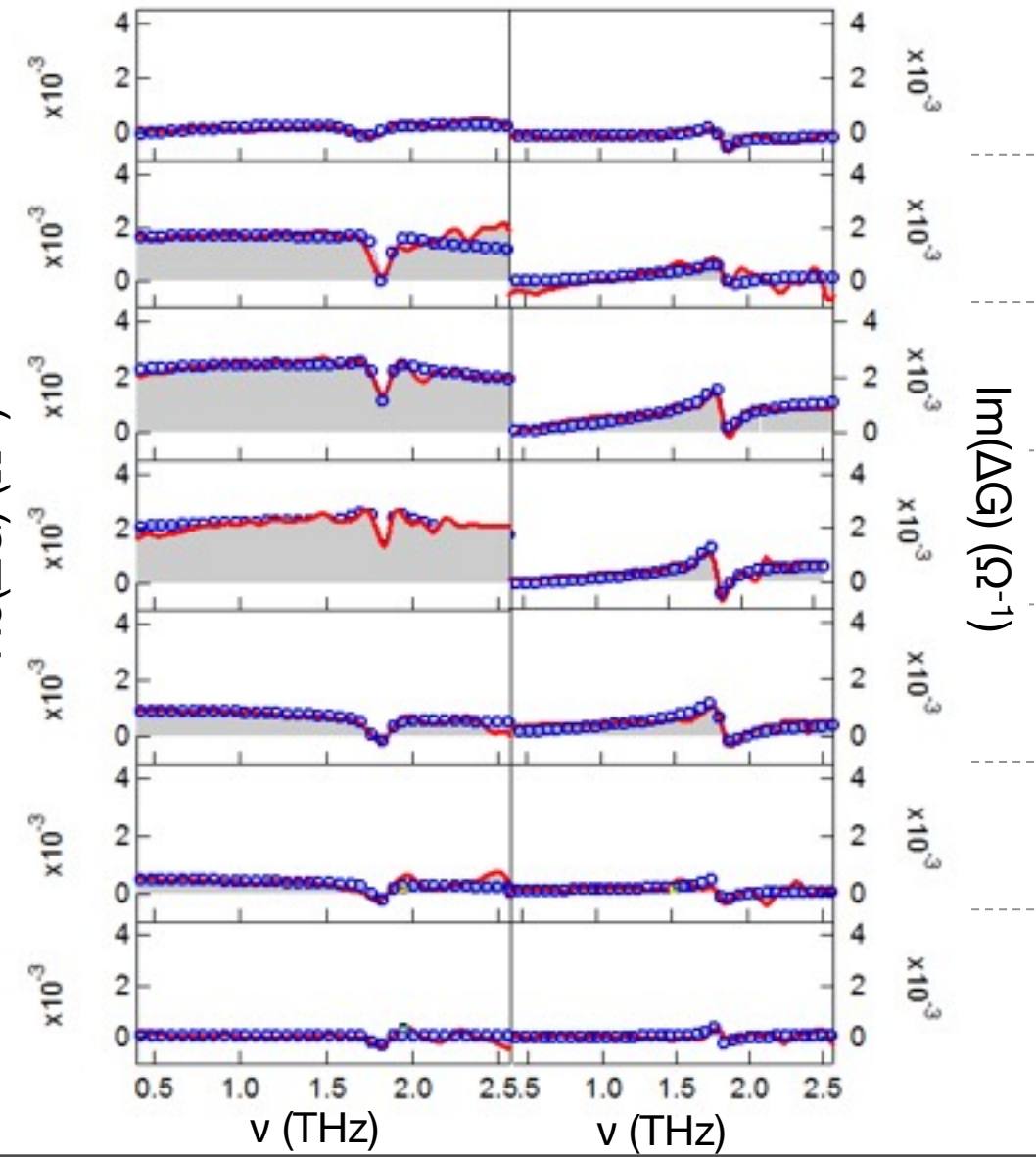
In collaboration with C. Hauri and C. Vicario, PSI (SW)

800 nm 650 $\mu\text{J}/\text{cm}^2$ 35 fs Pump – (0.4-2.5) THz

Plasmon Dynamics



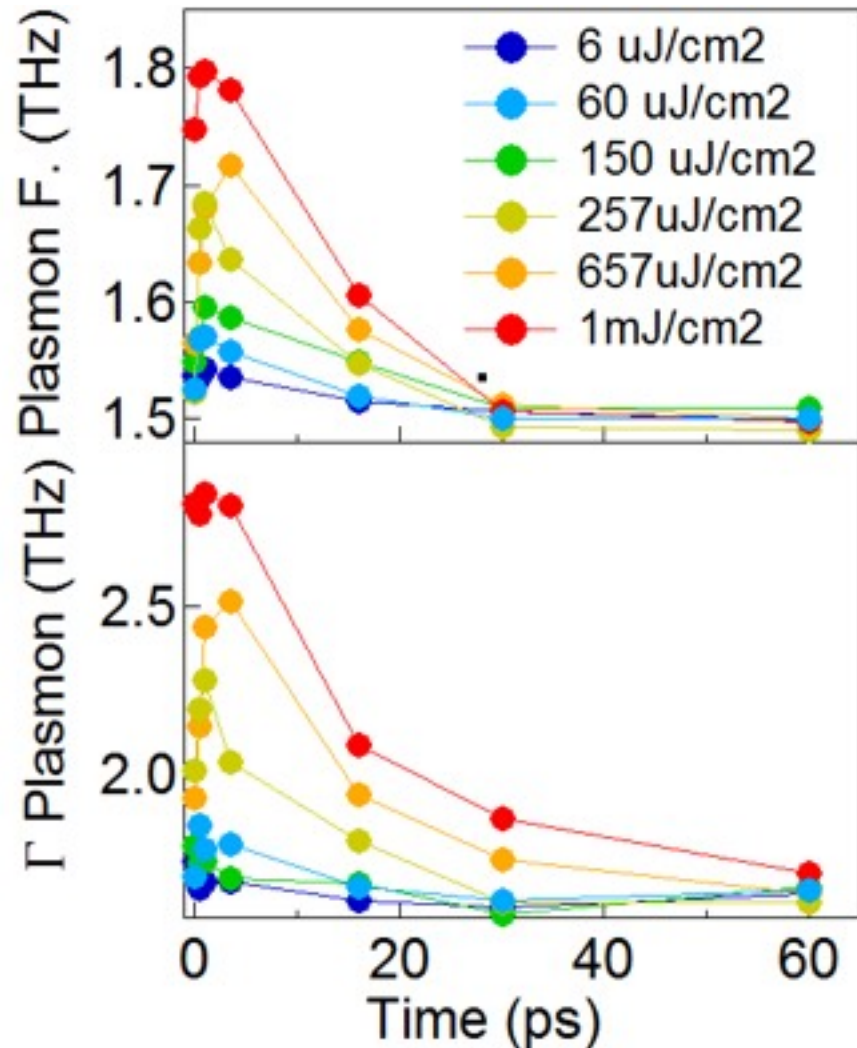
Single Particle Dynamics



Temporal Dynamics Vs Pump

Plasmon Dynamics

Evolution of Dirac Plasmon Parameters



Single Particle Dynamics

Evolution of Drude Parameters

